=> d allANSWER 1 OF 1 WPIDS COPYRIGHT 1997 DERWENT INFORMATION LTD L193-012571 [02] WPIDS ΑN Surround circuit for delaying digital signal by utilising RAM -ΤI reduces delayed RAM capacity necessary for surround process, thus reduces digital signal process and delayed RAM up to its formable level on same chip NoAbstract. T01 U22 W04 DC (NIDE) NEC CORP PΑ CYC 1 JP 04339500 A 921126 (9302)* H04S005-02 ΡI 4 pp JP 04339500 A JP 91-111364 910516 PRAI JP 91-111364 910516 ICM H04S005-02 ICS H03H017-02; H04S001-00 EPI FS NOAB; GI FΑ EPI: T01-J08B; U22-G01D; W04-R01C5; W04-R05 MC => fil japio FILE 'JAPIO' ENTERED AT 17:44:37 ON 21 APR 1997 COPYRIGHT (C) 1997 Japanese Patent Office (JPO) and Japan Patent Information Organization (Japio) FILE LAST UPDATED: 03 APR 97 <970403/UP> >>> THE PRICES FOR THIS FILE WILL BE CHANGED EFFECTIVE APRIL 1, 1997. -- SEE HELP COST OR HELP PRICE NEXT <<< => s 11 1 JP04339500/PN L2 => d all ANSWER 1 OF 1 JAPIO COPYRIGHT 1997 JPO and Japio .L2 92-339500 JAPIO ΑN SURROUNIING CIRCUIT TТ IN YAZAWA AKIRA PA NEC CORP, JP (CO 000423) JP 04339500 A 19921126 Heisei PΙ JP 91-111364 (JP03111364 Heisei) 19910516 ΑI PATENT ABSTRACTS OF JAPAN, Unexamined Applications, Section: E, SO Sect. No. 1350, Vol. 17, No. 192, P. 124 (19930414) ICM (5) H04S005-02 IC ICS (5) H03H017-02; (5) H04S001-00 (5) G10K015-12 ICA 42.5 ELECTRON - Applied electronic equipment 44.1 COMMUNICATION - Transmission circuit and antenna R104 APPLIED ELECTRONICS - 4 channel stereo CTPURPOSE: To faithfully reproduce the surrounding sound by writing a AB down- sampling signal of a sampling frequency in a delay RAM, and reading out the sampling frequency by executing over-sampling. CONSTITUTION: An audio input signal, is inputted to a digital signal processing circuit, its sampling frequency is lowered by a down-sampling converter, and it is written in a delay RAM. As a result, the written data quantity is reduced. Also, data read out of the delay RAM is subjected to over-sampling in reverse to the time of write and returned to its original sampling frequency. As a result, the capacity of the delay RAM required for a surrounding processing can be reduced, and a digital signal processing and the

delay RAM can be lowered to a level in which they can be formed on

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the same chip. In such a way, a surrounding sound can be reproduced faithfully.

أريا المماح فيالمنازفها المنادية المفاق وفاي رواست additional element is controlled at 0.005-1.0%. The grain size of the alloy is pref. adjusted to 0.015 mm or less by final annealing. The annealed alloy may be cold rolled with a work ratio of 3-20%. USE/ADVANTAGE - Useful as structural material of a heat exchanger, e.g. a steam condenser, a water heater or a cooler. The corrosion resistance of the alloy material esp. at its welded part is improved by the addition of Sn, Al and As or Sb. The corrosion resistance is further enhanced by making the grain size smaller. The addn. elements such as B, Ni, Si, etc. improve the mechanical strength of the alloy without reducing the corrosion resistance. 0/2 CPI AΒ CPI: M26-B03; M26-B03A; M26-B03T; M26-B03Z COPYRIGHT 1997 DERWENT INFORMATION LTD ANSWER 6 OF 6 WPIDS 82-97679E [46] WPIDS Inexpensive copper alloy for electric contacts - contains germanium, antimony or gallium, and can replace costly silver alloys. L03 M26 P53 V03 X13 RAUTER, G; SCHULTZ, L; WILLHELM, M (SIEI) SIEMENS AG CYC 14 <--A 821110 (8246) * DE EP 64181 15 pp R: AT DE FR GB IT NL SE DE 3116680 A 821118 (8247) JP 57181348 A 821108 (8250) NO 8201339 A 821122 (8250) FI 8200583 A 821231 (8307) 830118 (8310) PT 74797 Α DK 8201843 A 830314 (8317) ZA 8202858 A 830124 (8317) <--EP 64181 в 850213 (8507) R: AT BE FR GB IT NL SE DE 3262286 G 850328 (8514) ADT EP 64181 A EP 82-103118 820413 PRAI DE 81-3116680 810427 2.Jnl.Ref ; DE 1289991; FR 2294527; FR 2428904; GB 1084351; JP 52020288; JP 52030217 B22F003-00; C22C009-00; H01H001-02 64181 A UPAB: 930915 The alloy is used esp. for low voltage switches, and switchgear used in electric wiring systems, and contains Cu with at least one of the elements Sb, Ga, Ge, which are present in atomic percent in the amts. 0.01-7% Sb; 0.5-20% Ga; and 0.5-10% Ge. The alloy may also contain (in atomic %) 0.1-2% Cd; 0.01-0.8% Cr; 0.1-1.8% Co; 0.1-3% Pd; and/or 0.5-10% Si, the amts. of these additional elements should not exceed the amt. of Sb, Ga, and/or Ge present. The esp. pref. alloy contains 3-7 esp. 5% Ge, and is made by melting in an inert gas, then heat-treated at 600-950 deg.C. Alternatively, the alloys may be made by powder metallurgy, the compacts being heated to cause diffusion in the solid state. The alloy can replace expensive Ag contact alloys. CPI EPI GMPI AB CPI: L03-A01A; L03-B04; M26-B03; M26-B03A; M26-B03S; M26-B03X EPI: V03-A01; X13-A01

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WPIDS 93-012571 [02] AN

FS

FΑ

MC

L2

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ΤI

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Surround circuit for delaying digital signal by utilising RAM -ΤI reduces delayed RAM capacity necessary for surround process, thus reduces digital signal process and delayed RAM up to its formable level on same chip NoAbstract.